

Ordering number : ENN7296

P-Channel Silicon MOSFET

2SJ613



Ultrahigh-Speed Switching Applications

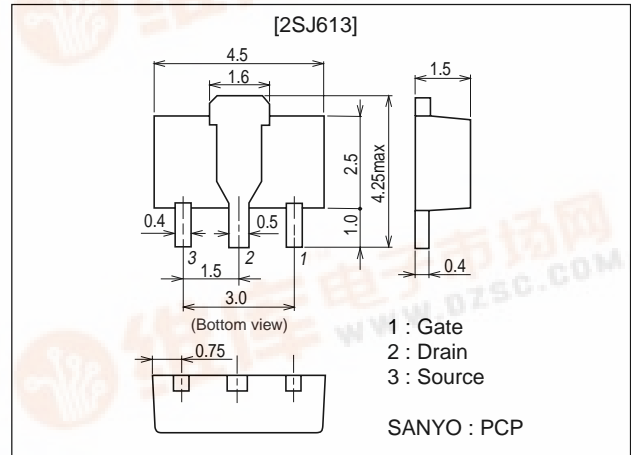
Features

- Low ON-resistance.
- Ultrahigh-speed switching.
- 2.5V drive.

Package Dimensions

unit : mm

2062A



Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	V _{DSS}		-20	V
Gate-to-Source Voltage	V _{GSS}		±10	V
Drain Current (DC)	I _D		-6	A
Drain Current (Pulse)	I _{DP}	PW≤10μs, duty cycle≤1%	-24	A
Allowable Power Dissipation	P _D	Mounted on a ceramic board (250mm ² ×0.8mm)	1.5	W
		T _c =25°C	3.5	W
Channel Temperature	T _{ch}		150	°C
Storage Temperature	T _{stg}		-55 to +150	°C

Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Drain-to-Source Breakdown Voltage	V _{(BR)DSS}	I _D =-1mA, V _{GS} =0	-20			V
Zero-Gate Voltage Drain Current	I _{DSS}	V _{DS} =-20V, V _{GS} =0			-1	μA
Gate-to-Source Leakage Current	I _{GSS}	V _{GS} =±8V, V _{DS} =0			±10	μA
Cutoff Voltage	V _{GS(off)}	V _{DS} =-10V, I _D =-1mA	-0.4		-1.3	V
Forward Transfer Admittance	y _{fs}	V _{DS} =-10V, I _D =-3A	4.6	6.6		S
Static Drain-to-Source On-State Resistance	R _{DS(on)1}	I _D =-3A, V _{GS} =-4V		53	69	mΩ
	R _{DS(on)2}	I _D =-1.5A, V _{GS} =-2.5V		72	98	mΩ

Marking : JT

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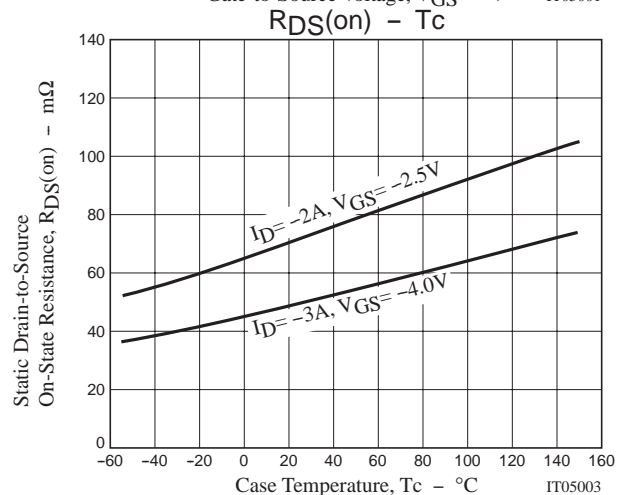
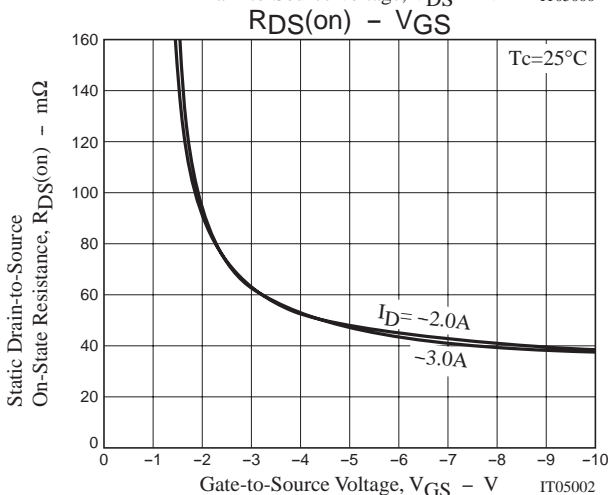
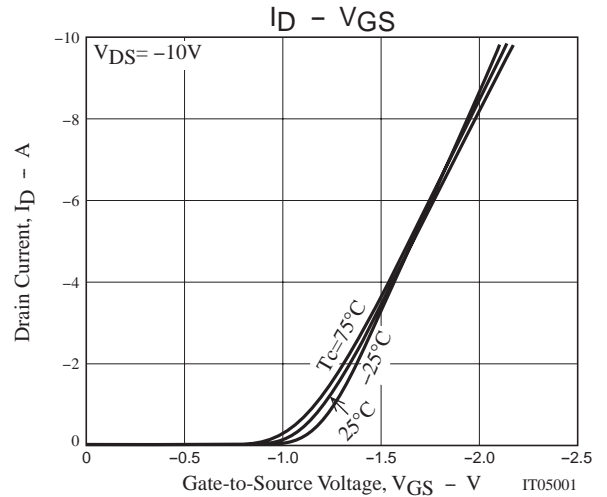
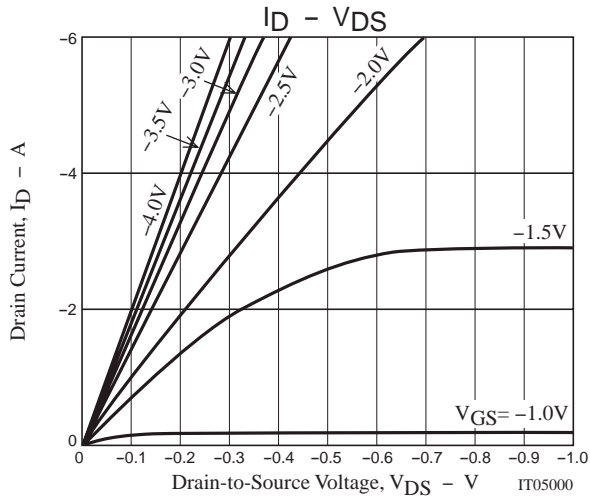
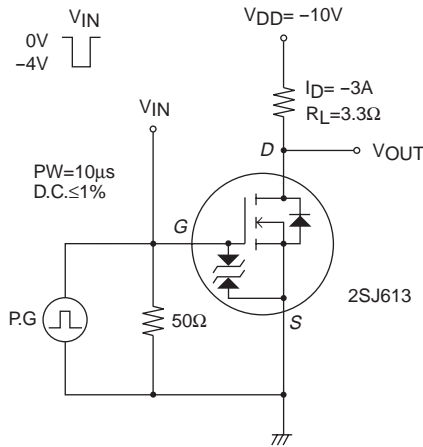


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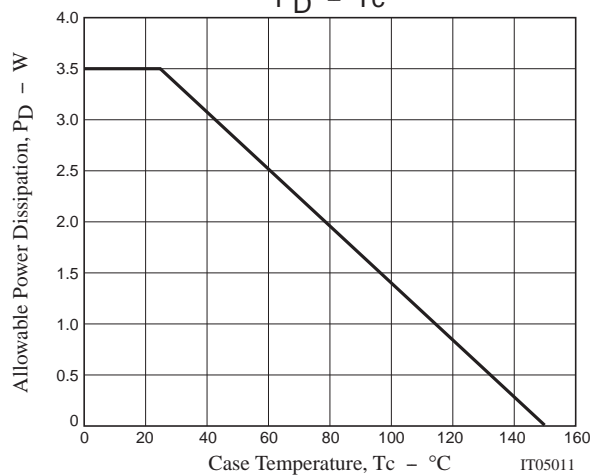
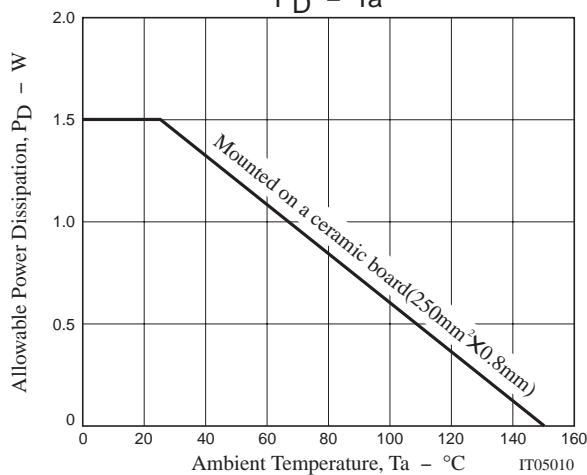
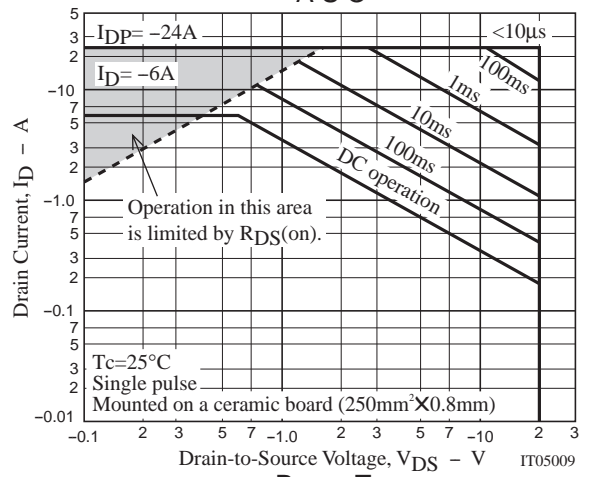
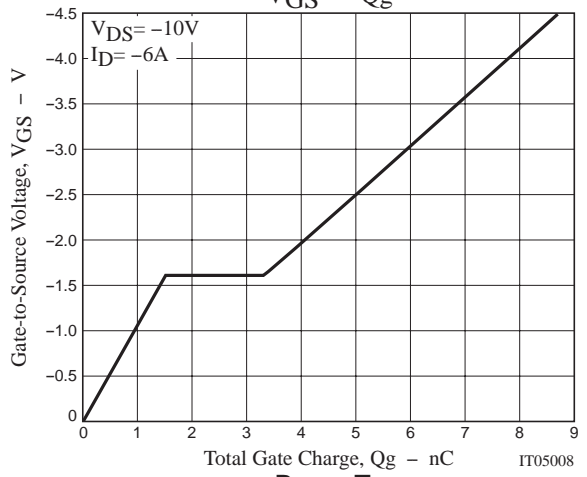
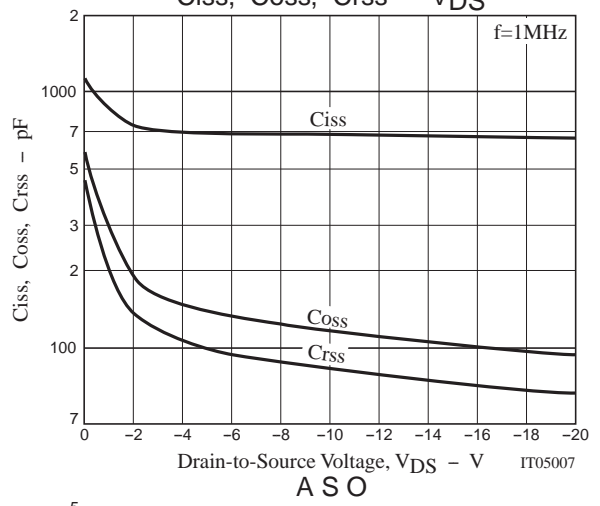
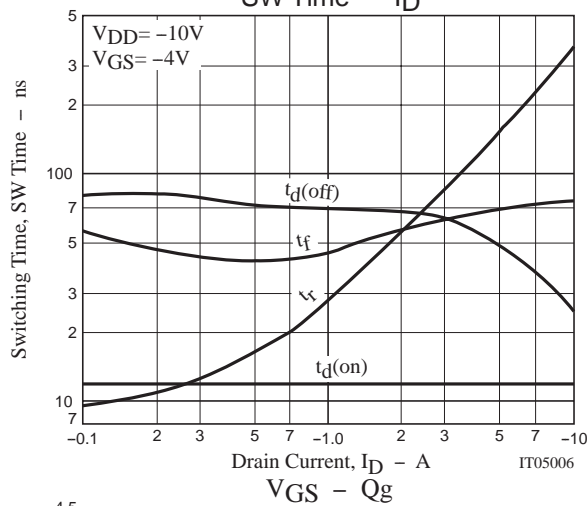
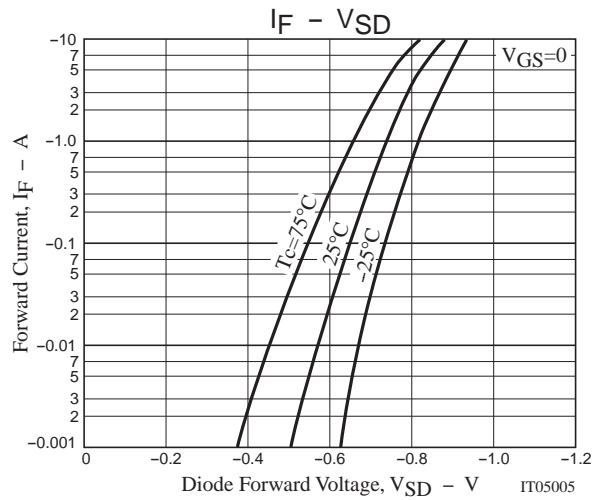
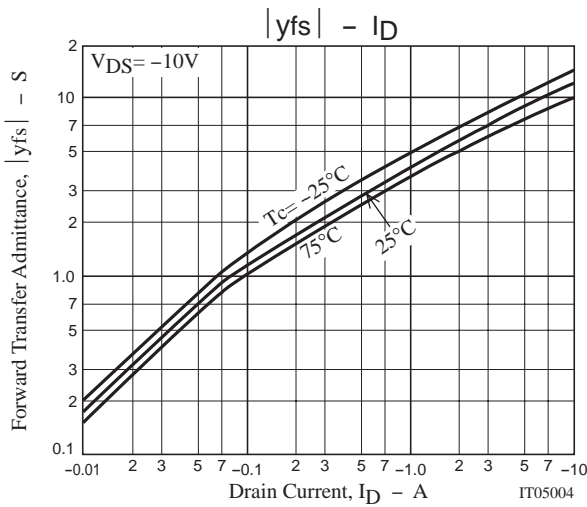
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Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Input Capacitance	Ciss	V _{DS} =-10V, f=1MHz		680		pF
Output Capacitance	Coss	V _{DS} =-10V, f=1MHz		115		pF
Reverse Transfer Capacitance	Crss	V _{DS} =-10V, f=1MHz		80		pF
Turn-ON Delay Time	t _{d(on)}	See specified Test Circuit.		12		ns
Rise Time	t _r	See specified Test Circuit.		88		ns
Turn-OFF Delay Time	t _{d(off)}	See specified Test Circuit.		62		ns
Fall Time	t _f	See specified Test Circuit.		63		ns
Total Gate Charge	Q _g	V _{DS} =-10V, V _{GS} =-4V, I _D =-6A		7.8		nC
Gate-to-Source Charge	Q _{gs}	V _{DS} =-10V, V _{GS} =-4V, I _D =-6A		1.5		nC
Gate-to-Drain "Miller" Charge	Q _{gd}	V _{DS} =-10V, V _{GS} =-4V, I _D =-6A		1.8		nC
Diode Forward Voltage	V _{SD}	I _S =-6A, V _{GS} =0	-0.89		-1.5	V

Switching Time Test Circuit



2SJ613



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